

Amendments to the Specification:

Please replace the paragraph beginning on page 5, line 21, with the following paragraph:

--Referring now to the figures of the drawing in detail and first, particularly, to Fig. 1 thereof, there is seen a part of a power semiconductor element in the form of a thyristor. The thyristor comprises a semiconductor substrate 1 which, in the embodiment shown, is weakly n-doped, and which functions as an n<sup>-</sup>-basis semiconductor substrate. A p-basis 2 is connected to the n<sup>-</sup>-basis or semiconductor substrate 1, on the surface of which p-basis an n<sup>+</sup>-emitter structure 3 on the cathode side is arranged with cathode short circuits 4.--